imall

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N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)}	Package	Ι _D T _C = +25°C	
650V	1.3Ω @ V _{GS} = 10V	TO220AB	9.0A	

Description

This new generation complementary dual MOSFET features low onresistance and fast switching, making it ideal for high-efficiency power management applications.

Features

- Low Input Capacitance
- High BV_{DSS} Rating for Power Application
- Low Input/Output Leakage
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data Case: TO220AB



I. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

- Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

TO220AB



9N65CT = Product Type Marking Code AB = Foundry and Assembly Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 18 = 2018) WW = Week (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage				650	V
Gate-Source Voltage			V _{GSS}	±30	V
Continuous Drain Current (Note 5) V_{GS} = 10V	Steady State	T _C = +25°C T _C = +70°C	ID	9.0 7.0	А
Pulsed Drain Current (Note 6) 10µs Pulse, Pulse Duty Cycle<=1%			I _{DM}	30	A
Avalanche Current (Note 7) V_{DD} = 100V, V_{GS} = 10V, L = 60mH			I _{AR}	2.7	A
Repetitive Avalanche Energy (Note 7) $V_{DD} = 100V$, $V_{GS} = 10V$, L = 60mH			E _{AR}	260	mJ

Thermal Characteristics

Characteristic	Symbol	Max	Unit
Power Dissipation (Note 5) $T_C = +25^{\circ}C$ $T_C = +70^{\circ}C$	PD	165 100	w
Thermal Resistance, Junction to Case (Note 5)	Rejc	0.7	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV _{DSS}	650	—		V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current $T_J = +25^{\circ}C$	IDSS	_	—	1.0	μA	$V_{DS} = 650V, V_{GS} = 0V$	
Gate-Source Leakage	lgss			±100	nA	$V_{GS} = \pm 30V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(TH)}	3	—	5	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance	RDS(ON)	—	0.7	1.3	Ω	$V_{GS} = 10V, I_D = 4.5A$	
Forward Transfer Admittance	Y _{fs}		8.5		S	$V_{DS} = 40V, I_D = 4.5A$	
Diode Forward Voltage	V _{SD}	-	0.7	1.0	V	$V_{GS} = 0V, I_{S} = 1A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C _{iss}	—	2,310	_			
Output Capacitance	Coss	_	122	_	pF	V _{DS} = 25V, V _{GS} = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	Ι	2.2	-			
Gate Resistance	Rg	-	2.2		Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge V _{GS} = 10V	Qg	Ι	39	-			
Gate-Source Charge	Q _{gs}	_	8.5		nC	$V_{GS} = 10V, V_{DS} = 520V,$ $I_{D} = 8A$	
Gate-Drain Charge	Q _{gd}	Ι	11.9	-			
Turn-On Delay Time	t _{D(ON)}	Ι	39	—	ns		
Turn-On Rise Time	t _R	Ι	29	-	ns	$V_{GS} = 10V, V_{DS} = 325V,$	
Turn-Off Delay Time	tD(OFF)	—	122	_	ns	$R_G = 25\Omega, I_D = 8A$	
Turn-Off Fall Time	t _F	—	28	_	ns		
Body Diode Reverse Recovery Time	t _{RR}	—	570	_	ns	dl/dt = 100A/µs, V _{DS} = 100V,	
Body Diode Reverse Recovery Charge	Q _{RR}		4.17	_	μC	IF = 8A	

Notes: 5. Device mounted on an infinite heatsink.

6. Repetitive rating, pulse width limited by junction temperature.

7. IAR and EAR ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$. 8. Short duration pulse test used to minimize self-heating effect. 9. Guaranteed by design. Not subject to production testing.





NOT RECOMMENDED FOR NEW DESIGN -NO ALTERNATE PART

DMG9N65CT





TO220AB

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance. Note:





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